## NSN 5961-01-257-1236

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.570 inches
Overall Diameter:
0.235 inches
Function For Which Designed:
Transient suppressor
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-13
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
8.5 working peak reverse voltage and 9.5 breakdown voltage, dc and 10.5 breakdown voltage, dc
Current Rating Per Characteristic:
50.00 microamperes reverse current, dc
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius case
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
80131-release 6593 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0